UNISONIC TECHNOLOGIES CO., LTD

TIP127-Q

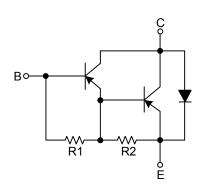
PNP SILICON TRANSISTOR

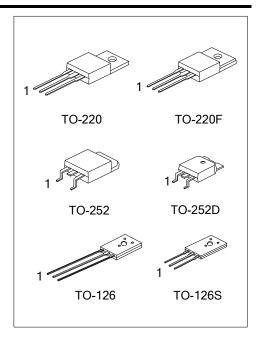
PNP EPITAXIAL TRANSISTOR

DESCRIPTION

The UTC TIP127-Q is a PNP epitaxial transistor, designed for use in general purpose amplifier low-speed switching applications.

EQUIVALENT TEST $(R_1 \approx 8k\Omega, R_2 \approx 0.12k\Omega)$

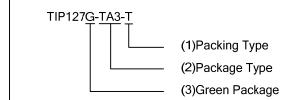




ORDERING INFORMATION

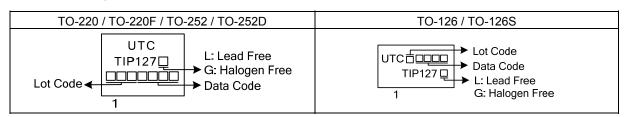
Ordering Number		Dooksass	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
TIP127L-TA3-T	TIP127G-TA3-T	TO-220	В	С	Е	Tube	
TIP127L-TF3-T	TIP127G-TF3-T	TO-220F	В	С	Е	Tube	
TIP127L-TN3-T	TIP127G-TN3-T	TO-252	В	С	Е	Tape Reel	
TIP127L-TND-R	TIP127G-TND-R	TO-252D	G	D	S	Tape Reel	
TIP127L-T60-K	TIP127G-T60-K	TO-126	Е	С	В	Bulk	
TIP127L-T6S-K	TIP127G-T6S-K	TO-126S	E	С	В	Bulk	

Note: Pin assignment: E: Emitter B: Base C: Collector



- (1) K: Bulk, T: Tube
- (2) TA3: TO-220, TF3: TO-220F, TN3: TO-252 TND: TO-252D, T60: TO-126, T6S: TO-126S
- (3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



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■ ABSOLUTE MAXIMUM RATING (T_C= 25°C, unless otherwise specified)

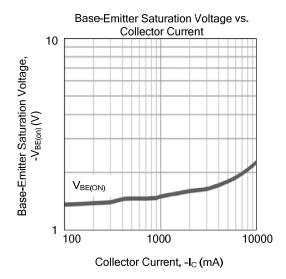
PARAMETER		SYMBOL RATINGS		UNIT
Collector to Base Voltage		V_{CBO}	-100	V
Collector to Emitter Voltage		V_{CEO}	-100	V
Emitter to Base Voltage		V_{EBO}	-5	V
Collector Current	DC	Ic	-5	Α
	Pulse	I _{CP}	-8	Α
Power Dissipation	TO-220		65	W
	TO-220F		34	W
	TO-252/TO-252D	$ P_{D}$	38	W
	TO-126/TO-126S		36	W
Junction Temperature		T_J	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

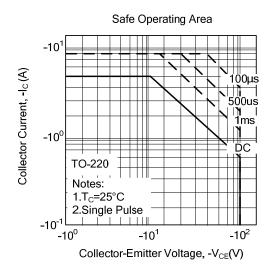
Note: Absolute maximum ratings are the values beyond which the device will be damaged permanently. Absolute maximum ratings are only stress ratings and it is not implied for functional device operation.

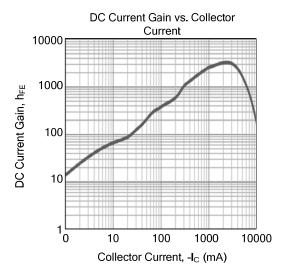
■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

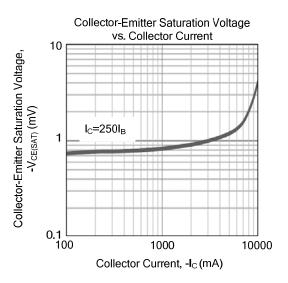
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =-10mA	-100			V
Collector Cut-Off Current	I _{CBO}	V _{CB} =-100V			-200	uA
Collector-Cut-Off Current	I _{CEO}	V _{CE} =-50V			-500	uA
Emitter Cut-Off Current	I _{EBO}	V _{EB} =-5V			-2	mA
Collector-Emitter Saturation Voltage	$V_{CE(SAT)1}$	I_C =-3A, I_B =-12mA			-2	V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)2}$	I _C =-5A, I _B =-20mA			-4	V
Base-Emitter Saturation Voltage	$V_{BE(ON)}$	V_{CE} =-3V, I_{C} =-3A			-2.5	V
DC Current Coin	l ncc	V_{CE} =-3V , I_{C} =-500mA	1000			
DC Current Gain		V_{CE} =-3V , I_{C} =-3A	1000			

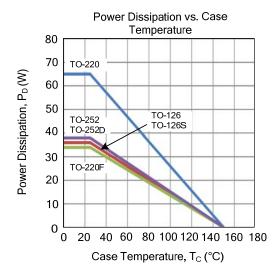
■ TYPICAL CHARACTERISTICS











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